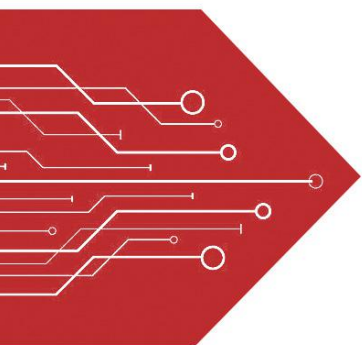


MSKSEMI

SEMICONDUCTOR



ESD



TVS



TSS



MOV



GDT



PLED

Product data sheet



SMC

FEATURES

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case: SMC
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.22g / 0.0077oz

Absolute Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Parameter	Symbols	SS1045	SS1060	SS10100	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	45	60	100	V
Maximum RMS voltage	V_{RMS}	32	42	70	V
Maximum DC Blocking Voltage	V_{DC}	45	60	100	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	10.0			A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	150			A
Max Instantaneous Forward Voltage @10.0 A	V_F	0.55	0.75	0.90	V
Maximum DC Reverse Current $T_j = 25^{\circ}\text{C}$ at Rated DC Reverse Voltage $T_j = 100^{\circ}\text{C}$	I_R	0.5 50			mA
Typical Thermal Resistance	$R_{\theta JA}$	20			$^{\circ}\text{C/W}$
Operating Junction Temperature Range	T_j	-55 ~ +150			$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	-55 ~ +150			$^{\circ}\text{C}$

(1) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

Fig.1 Forward Current Derating Curve

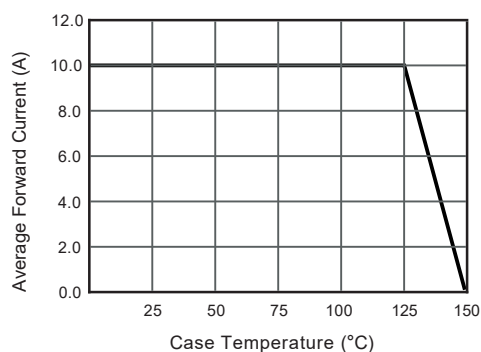


Fig.2 Typical Reverse Characteristics

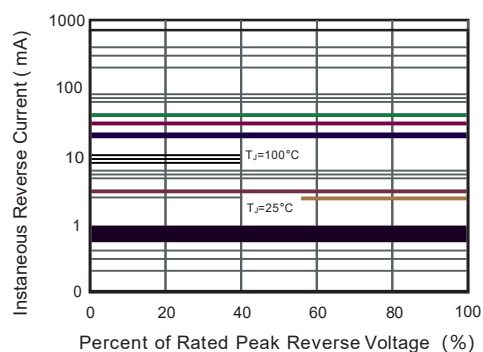


Fig.3 Typical Forward Characteristic

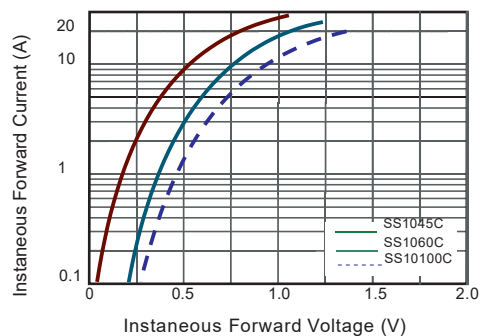


Fig.4- Typical Transient Thermal Impedance

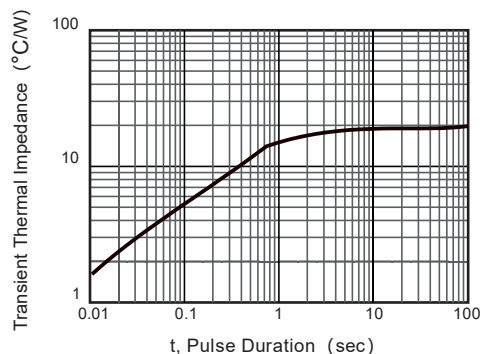
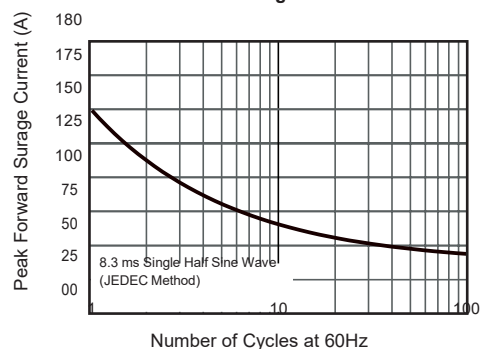
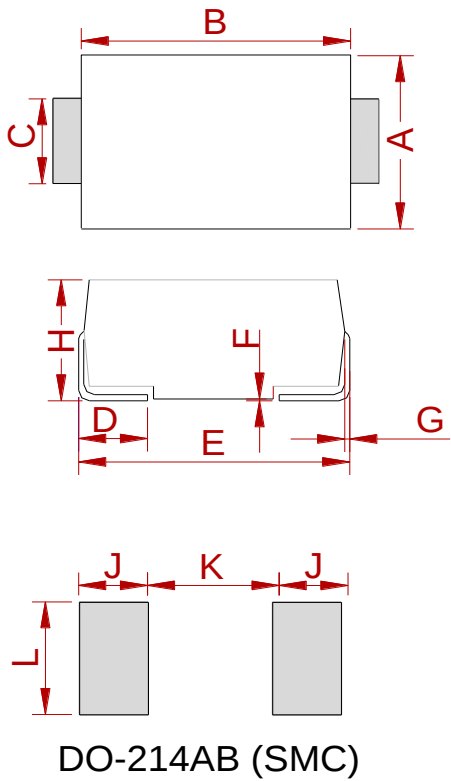


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current



PACKAGE MECHANICAL DATA



Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	5.75	6.25	0.226	0.246
B	6.90	7.40	0.272	0.291
C	2.75	3.25	0.108	0.128
D	0.95	1.52	0.037	0.060
E	7.70	8.20	0.303	0.323
F	0.051	0.203	0.002	0.008
G	0.15	0.31	0.006	0.012
H	2.15	2.62	0.085	0.103
J	2.40		0.094	
K		4.20		0.165
L	3.30		0.130	

REEL SPECIFICATION

P/N	PKG	QTY
SS1045 THRU SS10100	SMC	3000

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